QUICKSWITCH® PRODUCTS HIGH-PERFORMANCE CMOS SIX CHANNEL SP4T MUX/DEMUX

FEATURES:

- Low ON resistance: $r_{DS}(o_N) = 5\Omega$
- Fast transition time: ttran = 6ns
- · Wide bandwidth: 700MHz (-3dB point)
- · Crosstalk: -110dB at 50KHz, -68dB at 5MHz, -66dB at 30MHz
- · Off-isolation: -90dB at 50KHz, -60dB at 5MHz, -50dB at 30MHz
- · Single 5V supply
- · Can be used as multiplexer or demultiplexer
- · TTL-compatible control inputs
- Ultra-low quiescent current: 9µA
- · Available in QVSOP package

APPLICATIONS:

- · High-speed video signal switching/routing
- · HDTV-quality video signal multiplexing
- Audio signal switching/routing
- Data acquisition
- ATE systems
- · Telecomm routing
- · Switch between multiple video sources
- · Token Ring transceivers
- · High-speed networking

DESCRIPTION:

The QS4A215 is a high-performance CMOS six-channel multiplexer/demultiplexer with individual enables. The low ON-resistance of the QS4A215 allows inputs to be connected to outputs with low insertion loss and high bandwidth. TTL-compatible control circuitry with "Break-Before-Make" feature prevents contention.

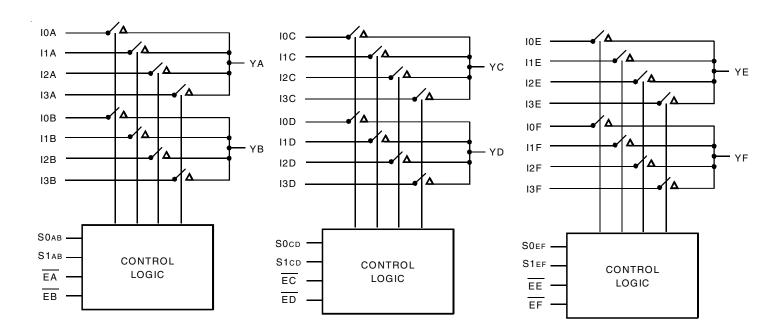
The QS4A215 with 700MHz bandwidth makes it ideal for high-performance video signal switching, audio signal switching, and telecom routing applications. High performance and low power dissipation makes this device ideal for battery operated and remote instrumentation applications.

The QS4A215 is offered in the QVSOP package which has several advantages over conventional packages such as PDIP and SOIC, including:

- Reduced signal delays due to denser component packaging on circuit boards
- Reduced system noise due to less pin inductance, resulting in lower ground bounce

The QS4A215 is characterized for operation at -40°C to +85°C.

FUNCTIONAL BLOCK DIAGRAM

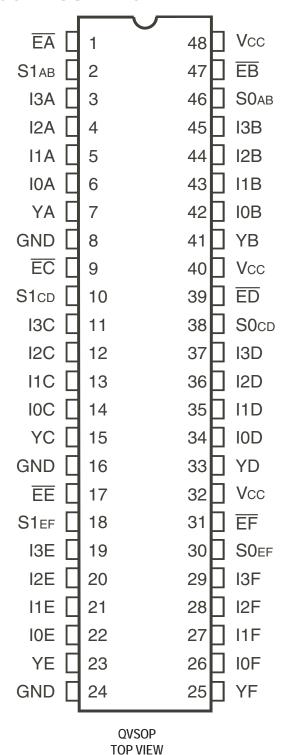


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INDUSTRIAL TEMPERATURE RANGE

JULY 2015

PIN CONFIGURATION



ABSOLUTE MAXIMUM RATINGS(1)

| Symbol | Description | Max | Unit |
|----------------------|--------------------------------------|-------------|------|
| VTERM ⁽²⁾ | Supply Voltage to Ground | -0.5 to +7 | V |
| VTERM ⁽³⁾ | DC Switch Voltage Vs | -0.5 to +7 | V |
| _ | Analog Input Voltage | -0.5 to +7 | V |
| VTERM ⁽³⁾ | DC Input Voltage VIN | -0.5 to +7 | V |
| VAC | AC Input Voltage (pulse width ≤20ns) | -3 | V |
| lout | DC Output Current | 120 | mA |
| Рмах | Maximum Power Dissipation | 0.7 | W |
| Tstg | Storage Temperature | -65 to +150 | °C |

NOTES:

- 1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- 2. Vcc terminals.
- 3. All terminals except Vcc .

PIN DESCRIPTION

| Pin Names | I/O | Description | | |
|------------|---------------------|-------------------|--|--|
| lxx | I/O Demux Ports A-F | | | |
| S0XX, S1XX | 1 | Select Inputs | | |
| Ēx | 1 | Enable Inputs A-F | | |
| Yx | I/O | Mux Ports A-F | | |

FUNCTION TABLE(1)

| Enable | | Select | | Mux/Demux | | |
|--------|----|--------|----------------|-----------|-----|----------------|
| | _ | | | Ports | | |
| ĒĀ | ĒΒ | S1 | S ₀ | YA | YB | Function |
| Н | Χ | Χ | Χ | Z | Х | Disable A |
| Χ | Н | Х | Χ | Х | Z | Disable B |
| L | L | L | L | IoA | IoB | S1AB, S0AB = 0 |
| L | L | L | Н | I1A | I1B | S1AB, S0AB = 1 |
| L | L | Н | L | I2A | I2B | S1AB, S0AB = 2 |
| L | L | Н | Н | ІзА | ІзВ | S1AB, S0AB = 3 |

NOTE:

- 1. H = HIGH Voltage Level
 - L = LOW Voltage Level
- X = Don't Care
- Z = High-Impedance
- This function table represents the function for block "AB". The "CD" block nomenclature substitutes "A" for "C" and "B" for "D". The "EF" block nomenclature substitutes "A" for "E" and "B" for "F".

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Industrial: TA = -40°C to +85°C, Vcc = $5V \pm 5\%$

| Symbol | Parameter | Test Conditions | Min. | Typ. ⁽¹⁾ | Max. | Unit |
|----------------------|---|---|------|---------------------|---------|------|
| Analog Si | vitch | | | | | |
| Vin | Analog Signal Range ⁽²⁾ | | -0.5 | 1 | Vcc - 1 | V |
| rds(on) | Drain-source ON resistance ^(2,3) | Vcc = Min., Vin = 0V, Ion = 30mA | | 5 | 7 | Ω |
| | | Vcc = Min., VIN = 2.4V, ION = 15mA | _ | 13 | 17 | |
| IC(OFF) | Channel Off Leakage Current | In = Vcc or 0V; Yn = 0V or Vcc; \overline{EX} = Vcc | | 10 | _ | nA |
| IC(ON) | Channel On Leakage Current | $I_N = Y_N = 0V$ | _ | 10 | _ | nA |
| | | (each channel is turned on sequentially) | | | | |
| Digital Co | ntrol | | | | | |
| Vih | Input HIGH Voltage | Guaranteed Logic HIGH for Control Pins | 2 | - | _ | V |
| VIL | Input LOW Voltage | Guaranteed Logic LOW for Control Pins | _ | _ | 0.8 | V |
| Dynamic (| Characteristics | | • | | | |
| ttrans | Switching Time of Mux | $RL = 1K\Omega$, $CL = 100pF$ | 0.5 | _ | 6.6 | ns |
| | Sx to Yx | (See Transition Time) | | | | |
| ton(EN) | Enable Turn-On Time | $RL = 1K\Omega$, $CL = 100pF$ | 0.5 | _ | 6 | ns |
| | \overline{EX} to Yx | (See Switching Time) | | | | |
| toff(EN) | Enable Turn-Off Time | $RL = 1K\Omega$, $CL = 100pF$ | 0.5 | _ | 6 | ns |
| | \overline{EX} to Yx | (See Switching Time) | | | | |
| t PD | Group Delay ^(2,4) | $RL = 1K\Omega$, $CL = 100pF$ | _ | - | 250 | ps |
| f3dB | -3dB Bandwidth | VIN = 1Vp-p, RL = 75Ω | _ | 700 | _ | MHz |
| | Off-isolation | VIN = 1Vp-p, RL = 75Ω , f = $5MHz$ | _ | -60 | _ | dB |
| XTALK | Crosstalk | VIN = 1Vp-p, RL = 75Ω , f = $5MHz$ | _ | -68 | _ | dB |
| CMUX(OFF) | Mux Off Capacitance | EX = Vcc, VIN = VOUT = 0V | _ | 6 | _ | pF |
| DEMUX(OFF) | Demux Off Capacitance | EX = Vcc, Vin = Vout = 0V | _ | 14 | _ | pF |
| CMUX(ON) | Mux On Capacitance | $\overline{\text{EX}}$ = 0V, VIN = VOUT = 0V | _ | 20 | _ | pF |
| CDEMUX(ON) | Demux On Capacitance | $\overline{\text{EX}}$ = 0V, VIN = VOUT = 0V | | 20 | _ | pF |
| Qcı | Charge Injection | CL = 1000pF | | 1.5 | _ | рC |

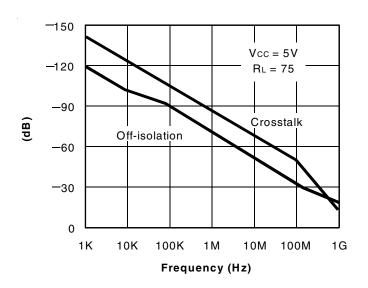
NOTES:

- 1. Typical values are at Vcc = 5.0V, Ta = 25°C.
- 2. Max value is guaranteed but not production tested.
- 3. Measured by voltage drop between A and C pins or B and D pins at indicated current through the switch. ON resistance is determined by the lower of the voltages on the two (I, Y) pins.
- 4. The bus switch contributes no group delay other than the RC delay of the ON resistance of the switch and load capacitance. Group delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

POWER SUPPLY CHARACTERISTICS

| Symbol | Parameter | Test Conditions | Max. | Unit |
|--------|-----------------|-------------------------------------|------|------|
| Iccq | Quiescent Power | Vcc = Max., Vin = GND or Vcc, f = 0 | 9 | μΑ |

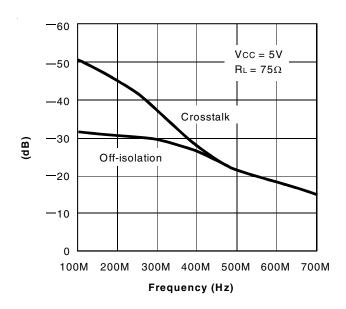
TYPICAL CHARACTERISTICS



Off-isolation and Crosstalk vs. Frequency

NOTES:

- 1. Crosstalk = 20 log |Vo/Vs|
- 2. Off-isolation = 20 log |Vo/Vs|



Off-isolation and Crosstalk vs. Frequency

NOTES:

- 1. Crosstalk = 20 log |Vo/Vs|
- 2. Off-isolation = 20 log |Vo/Vs|

4

2

0

-2

-6

1K

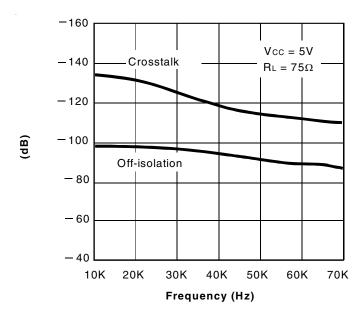
(dB)

 $R_L = 1 K\Omega$

 $RL = 75\Omega$

Vcc = 5V

10K



Off-isolation and Crosstalk vs. Frequency

Insertion Loss vs. Frequency

1M

Frequency (Hz)

10M

100M

1G

100K

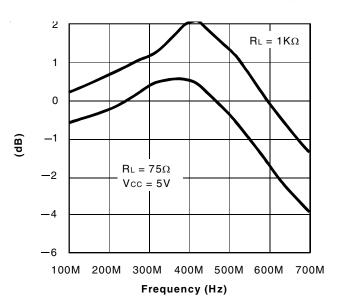
NOTE:

1. Insertion Loss = 20 log |Vo/Vs|

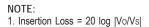
NOTES:

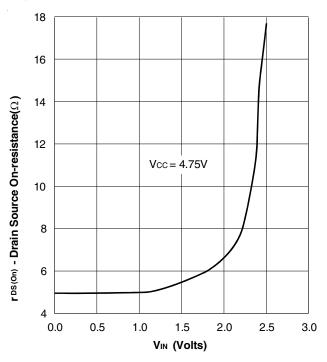
- 1. Crosstalk = 20 log |Vo/Vs|
- 2. Off-isolation = 20 log |Vo/Vs|

TYPICAL CHARACTERISTICS (CONTINUED)



Insertion Loss vs. Frequency

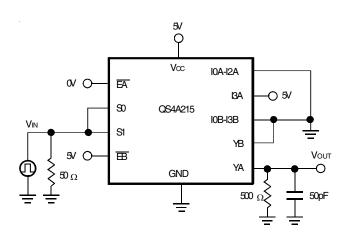


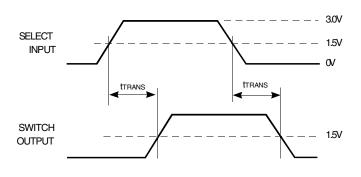


On-Resistance vs. VIN

Ron LINK

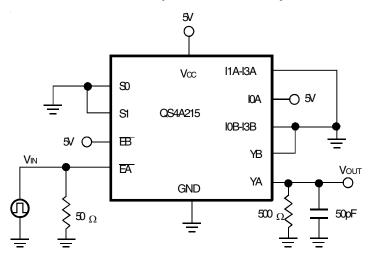
TEST CIRCUITS

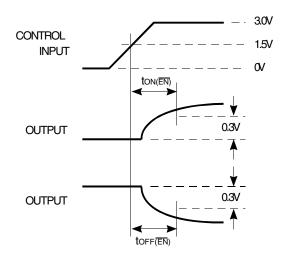




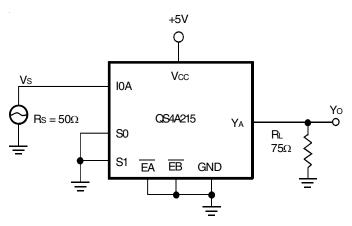
Transition Time

TEST CIRCUITS (CONTINUED)

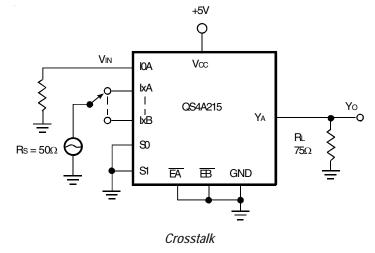




Enable Switching Time



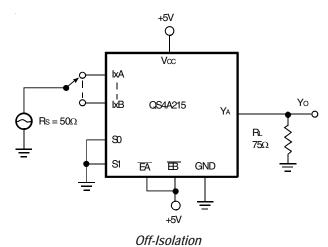
Insertion Loss



NOTE:

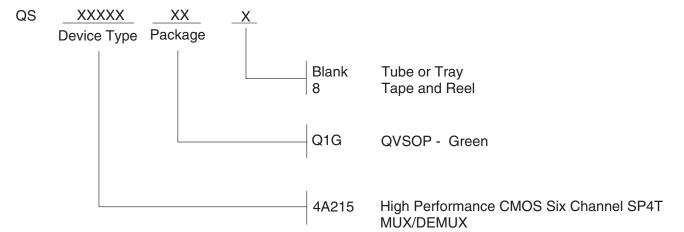
1. Insertion Loss = 20 log |Vo/Vs|





NOTE:

ORDERING INFORMATION



DATASHEET DOCUMENT HISTORY

| 04/13/2014 | Pg. 7 | Updated the Ordering Information by removing non green package version, the "IDT" notation and Adding Tape |
|------------|-------|--|
| | | and Reel information. |
| 07/07/2015 | Pa 17 | Undated the Ordering Information from OG to O1G accordingly |

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